What is claimed is:

A method for chemical-mechanical polishing a wafer using a CMP apparatus having a polishing table including a polishing pad and a wafer carrier adapted to carry a

- wafer relative to the center of the polishing table, the method comprising:
- 4 \ using the polishing pad and polishing the wafer at a position relative to the
- 5 center;
- determining that the wafer is being polished in a center-offset manner; and
- 7 conditioning the pad as a function of the wafer being polished in the center-
- 8 offset manner.
- 1 2. A method for chemical-mechanical polishing, according to claim 1, wherein the
- 2 center-offset manner includes at least one of: a center-fast or center-slow manner, and
- 3 further including inspecting a wafer during the polishing process.
- 1 3. A method for chemical-mechanical polishing, according to claim 1, wherein
- determining that the wafer is being polished in a center-offset manner includes
- 3 removing the wafer from the carrier and manually inspecting a wafer.
- 1 4. A method for chemical-mechanical polishing, according to claim 1, wherein the
- 2 wafer is being polished in a center-fast manner, and further including arranging a
- 3 conditioning wheel over the pad and relative to the center of the polishing table.

1 5. A method for chemical-mechanical polishing, according to claim 4, wherein

- 2 arranging the conditioning wheel comprises thinning the center of the pad.
- 1 6. A method for chemical-mechanical polishing, according to claim 1, wherein the
- 2 wafer is being polished in a center-slow manner, and further including arranging a
- 3 conditioning wheel over the pad and relative to the center of the polishing table.
- 7. A method for chemical-mechanical polishing, according to claim 6, wherein
- 2 arranging the conditioning wheel comprises thinning the edge of the pad.
- 1 8. A method for chemical-mechanical polishing, according to claim 1, wherein
- 2 conditioning the pad comprises altering the thickness of the pad in at least one location.
- 9. A method for chemical-mechanical polishing, according to claim 8, wherein
- 2 altering the thickness of the pad comprises thinning the pad in at least one location
- where the pad is thick relative to the rest of the pad.

10. A method for chemical-mechanical polishing, according to claim 8, wherein altering the thickness of the pad comprises applying increased pressure to a portion of

3 the pad with the wheel.

1 11.\ An arrangement for chemical-mechanical polishing a wafer, the arrangement

means for polishing a wafer;

comprising:

- 4 means for holding a wafer face-down on the means for polishing;
- 5 means for determining whether the wafer is polishing in a center-offset manner;
- 6 and

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- 7 means for conditioning the pad responsive to the means for determining whether
- the wafer is polishing in a center-offset manner.
- 1 12. An arrangement for chemical-mechanical polishing, the arrangement
- 2 comprising:
- a polishing pad arranged to rotate;
- a wafer carried arranged to carry a wafer, rotate, and hold the wafer face-down
- on the polishing pad;
- a detection arrangement adapted to detect whether the wafer is polishing in a
- 7 center-offset manner.
- a conditioning devide arranged to condition the pad, responsive to the detection
- 9 arrangement.
- 1 13. An arrangement for chemical-mechanical polishing, according to claim 12,
- wherein the conditioning wheel is further arranged relative to the center of the polishing

- table as a function of whether the wafer is polishing in a center-fast or center-slow
- 4 manner.
- 1 14. An arrangement for chemical-mechanical polishing, according to claim 12,
- 2 further comprising a supply arranged to supply conditioning material to the polishing
- 3 pad.
- 1 15. An arrangement for chemical-mechanical polishing, according to claim 14,
- wherein the conditioning material is supplied responsive to the detection arrangement.
- 1 16. An arrangement for chemical-mechanical polishing, according to claim 15,
- wherein the conditioning material comprises water.

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